

3-TERMINAL POSITIVE VOLTAGE REGULATOR

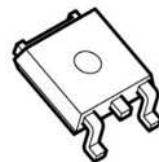
■ GENERAL DESCRIPTION

The NJM78M00S is a 0.5A output 3-Terminal Positive Voltage Regulator.

It has improvements in contrast with a conventional NJM78M00:

An output voltage accuracy, an operating temperature range and MLCC correspondence.

■ PACKAGE OUTLINE

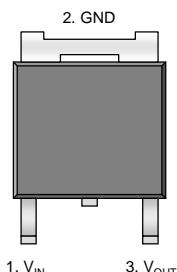


NJM78M00SDL1
(TO-252-3)

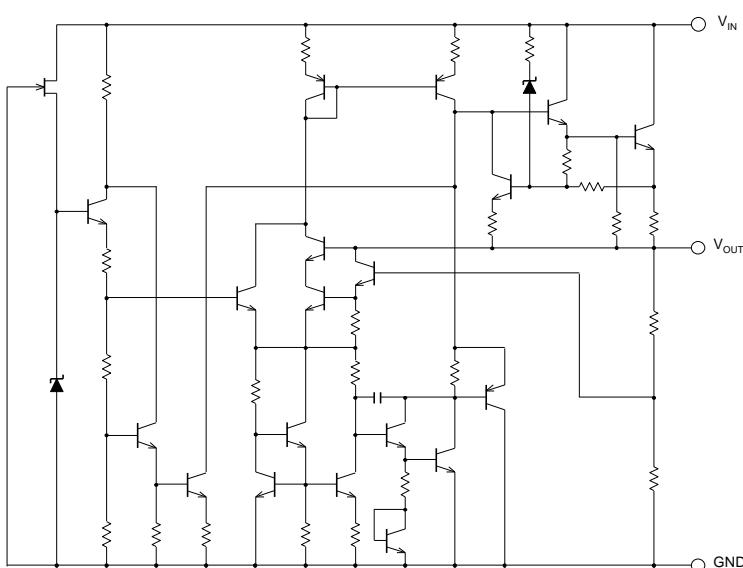
■ FEATURES

- Output Current 0.5A max.
- Output Voltage Accuracy $V_O \pm 3.0\%$
- High Ripple Rejection
- Correspond to Low ESR Capacitor (MLCC)
- Over Current Protection Circuit
- Thermal Shutdown Circuit
- Output Voltage Lineup 5V, 9V, 12V, 15V
- Package TO-252-3

■ PIN CONFIGURATION



■ EQUIVALENT CIRCUIT



NJM78M00S

■ ABSOLUTE MAXIMUM RATINGS

(Unless otherwise noted, $T_a = 25^\circ\text{C}$)

PARAMETER	SYMBOL	MAXIMUM RATINGS	UNIT
Input Voltage	V_{IN}	35	V
Power Dissipation	P_D	1190 (*1) 3125 (*2)	mW
Junction Temperature Range	T_J	- 40 to + 150	°C
Operating Temperature Range	T_{opr}	- 40 to + 125	°C
Storage Temperature Range	T_{stg}	- 50 to + 150	°C

(*1) Mounted on glass epoxy board. (76.2×114.3×1.6mm:EIA/JDEC standard size, 2Layers, copper area 100mm²)

(*2) Mounted on glass epoxy board. (76.2×114.3×1.6mm:EIA/JDEC standard size, 4Layers)

(4Layers inner foil: 74.2 ×74.2mm applying a thermal via hole to a board based on JEDEC standard JESD51-5)

■ ELECTRICAL CHARACTERISTICS

($C_{IN}=0.33\mu\text{F}$, $C_O=0.1\mu\text{F}$, $T_j=25^\circ\text{C}$) Measurement is to be conducted is pulse testing.

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
NJM78M05SDL1						
Output Voltage	V_O	$V_{IN}=10\text{V}$, $I_O=0.35\text{A}$	4.85	5.0	5.15	V
Line Regulation	ΔV_O-V_{IN}	$V_{IN}=7\text{V}$ to 25V , $I_O=0.2\text{A}$	-	3	50	mV
Load Regulation	ΔV_O-I_O	$V_{IN}=10\text{V}$, $I_O=0.005\text{A}$ to 0.5A	-	5	50	mV
Quiescent Current	I_Q	$V_{IN}=10\text{V}$, $I_O=0\text{mA}$	-	4	6.0	mA
Average Temperature Coefficient of Output Voltage	$\Delta V_O/\Delta T$	$V_{IN}=10\text{V}$, $I_O=5\text{mA}$	-	-0.5	-	mV/°C
Ripple Rejection	RR	$V_{IN}=10\text{V}$, $I_O=0.35\text{A}$, $e_{in}=1\text{V}_{P-P}$, $f=120\text{Hz}$	60	80	-	dB
Output Noise Voltage	V_{NO}	$V_{IN}=10\text{V}$, $BW=10\text{Hz}$ to 100kHz , $I_O=0.35\text{A}$	-	60	-	μVrms
Dropout Voltage	ΔV_{IO}	$I_O=0.5\text{A}$	-	1.8	-	V

NJM78M09SDL1

Output Voltage	V_O	$V_{IN}=15\text{V}$, $I_O=0.35\text{A}$	8.73	9.0	9.27	V
Line Regulation	ΔV_O-V_{IN}	$V_{IN}=11.5\text{V}$ to 25V , $I_O=0.2\text{A}$	-	6	60	mV
Load Regulation	ΔV_O-I_O	$V_{IN}=15\text{V}$, $I_O=0.005\text{A}$ to 0.5A	-	8	90	mV
Quiescent Current	I_Q	$V_{IN}=15\text{V}$, $I_O=0\text{mA}$	-	4.1	6.0	mA
Average Temperature Coefficient of Output Voltage	$\Delta V_O/\Delta T$	$V_{IN}=15\text{V}$, $I_O=5\text{mA}$	-	-0.9	-	mV/°C
Ripple Rejection	RR	$V_{IN}=15\text{V}$, $I_O=0.35\text{A}$, $e_{in}=1\text{V}_{P-P}$, $f=120\text{Hz}$	56	70	-	dB
Output Noise Voltage	V_{NO}	$V_{IN}=15\text{V}$, $BW=10\text{Hz}$ to 100kHz , $I_O=0.35\text{A}$	-	90	-	μVrms
Dropout Voltage	ΔV_{IO}	$I_O=0.5\text{A}$	-	1.8	-	V

■ ELECTRICAL CHARACTERISTICS

(C_{IN}=0.33μF, C_O=0.1μF, T_j=25°C) Measurement is to be conducted in pulse testing.

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
NJM78M12SDL1						
Output Voltage	V _O	V _{IN} =19V, I _O =0.35A	11.64	12.0	12.36	V
Line Regulation	ΔV _O -V _{IN}	V _{IN} =14.5V to 30V, I _O =0.2A	-	8	60	mV
Load Regulation	ΔV _O -I _O	V _{IN} =19V, I _O =0.005A to 0.5A	-	8	120	mV
Quiescent Current	I _Q	V _{IN} =19V, I _O =0mA	-	4.1	6.0	mA
Average Temperature Coefficient of Output Voltage	ΔV _O /ΔT	V _{IN} =19V, I _O =5mA	-	-1.2	-	mV/°C
Ripple Rejection	RR	V _{IN} =19V, I _O =0.35A, e _{in} =1V _{P-P} , f=120Hz	55	70	-	dB
Output Noise Voltage	V _{NO}	V _{IN} =19V, BW=10Hz to 100kHz, I _O =0.35A	-	100	-	μVrms
Dropout Voltage	ΔV _{IO}	I _O =0.5A	-	1.8	-	V

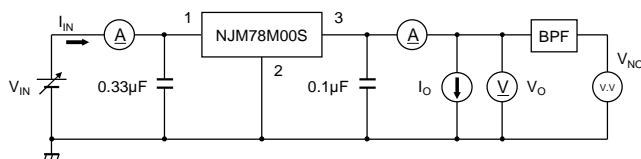
NJM78M15SDL1

Output Voltage	V _O	V _{IN} =23V, I _O =0.35A	14.55	15.0	15.45	V
Line Regulation	ΔV _O -V _{IN}	V _{IN} =17.5V to 30V, I _O =0.2A	-	10	60	mV
Load Regulation 1	ΔV _O -I _O	V _{IN} =23V, I _O =0.005A to 0.5A	-	10	150	mV
Quiescent Current	I _Q	V _{IN} =23V, I _O =0mA	-	4.1	6.0	mA
Average Temperature Coefficient of Output Voltage	ΔV _O /ΔT	V _{IN} =23V, I _O =5mA	-	-1.5	-	mV/°C
Ripple Rejection	RR	V _{IN} =23V, I _O =0.35A, e _{in} =1V _{P-P} , f=120Hz	54	70	-	dB
Output Noise Voltage	V _{NO}	V _{IN} =23V, BW=10Hz to 100kHz, I _O =0.35A	-	120	-	μVrms
Dropout Voltage	ΔV _{IO}	I _O =0.5A	-	1.8	-	V

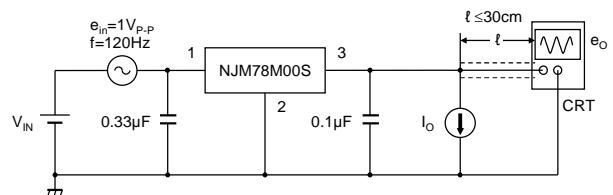
NJM78M00S

■ TEST CIRCUIT

1. Output Voltage, Line Regulation, Load Regulation,
Quiescent Current, Average, Output Noise Voltage,
Temperature Coefficient of Output Voltage,
Peak Output/Short Circuit Current



2. Ripple Rejection



- Measurement is to be conducted in pulse testing
- I_Q=I_{IN} - I_O

$$RR = 20 \log_{10} \left(\frac{e_{in}}{e_o} \right)$$

• Input Capacitor C_{IN}

Input Capacitor C_{IN} is required to prevent oscillation and reduce power supply ripple for applications when high power supply impedance or a long power supply line.

Therefore, use the recommended C_{IN} value (refer to conditions of ELECTRIC CHARACTERISTIC) or larger and should connect between GND and V_{IN} as shortest path as possible to avoid the problem.

• Output Capacitor C_O

Output capacitor (C_O) will be required for a phase compensation of the internal error amplifier.

The capacitance and the equivalent series resistance (ESR) influence to stable operation of the regulator.

Use of a smaller C_O may cause excess output noise or oscillation of the regulator due to lack of the phase compensation.

On the other hand, Use of a larger C_O reduces output noise and ripple output, and also improves output transient response when rapid load change.

Therefore, use the recommended C_O value (refer to conditions of ELECTRIC CHARACTERISTIC) or larger and should connect between GND and V_{OUT} as shortest path as possible for stable operation.

In addition, you should consider varied characteristics of capacitor (a frequency characteristic, a temperature characteristic, a DC bias characteristic and so on) and unevenness peculiar to a capacitor supplier enough.

When selecting C_O, recommend that have withstand voltage margin against output voltage and superior temperature characteristic though this product is designed stability works with wide range ESR of capacitor including low ESR products.

■ THERMAL RESISTANCE CHARACTERISTICS

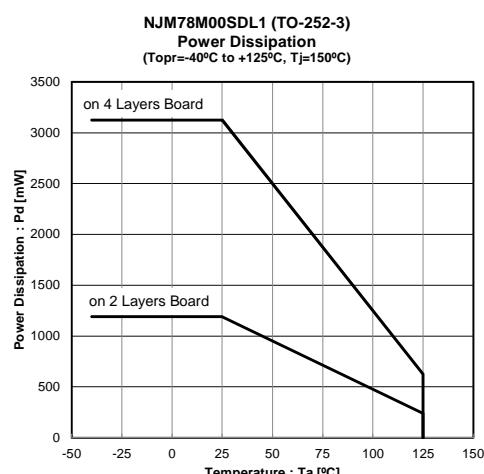
PARAMETER	SYMBOL	VALUE	UNIT
Junction-to-Ambient Thermal Resistance	θ_{ja}	105 (*1) 40 (*2)	°C/W
Junction-to-Top of Package Characterization Parameter	Ψ_{jt}	17 (*1) 12 (*2)	°C/W

(*1) Mounted on glass epoxy board. (76.2×114.3×1.6mm:EIA/JDEC standard size, 2Layers, copper area 100mm²)

(*2) Mounted on glass epoxy board. (76.2×114.3×1.6mm:EIA/JDEC standard size, 4Layers)

(4Layers inner foil: 74.2 ×74.2mm applying a thermal via hole to a board based on JEDEC standard JESD51-5)

■ AMBIENT TEMPERATURE vs. POWER DISSIPATION



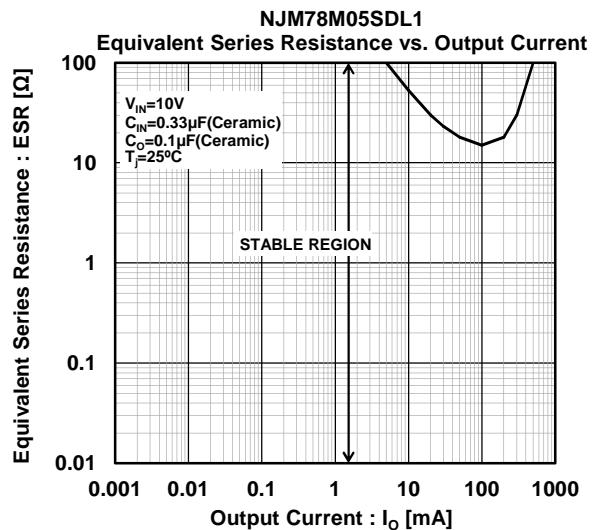
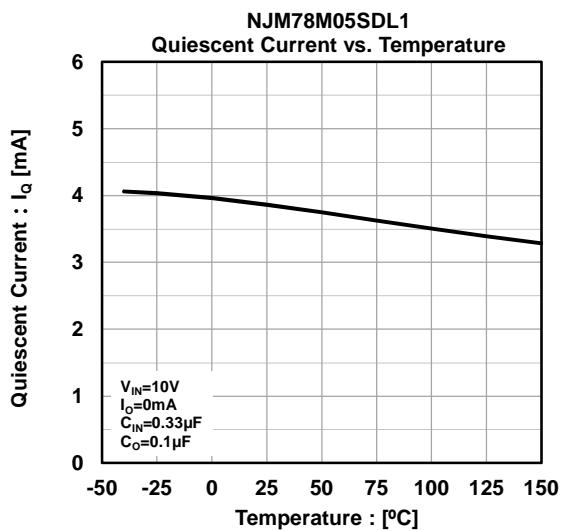
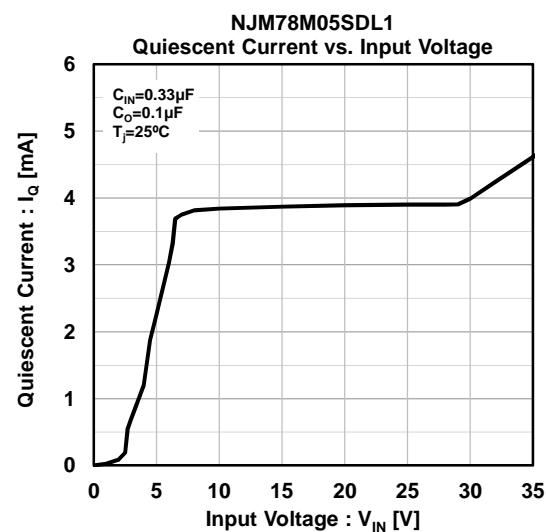
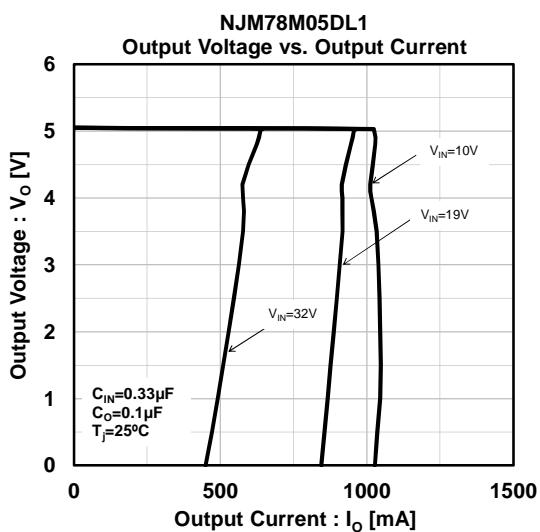
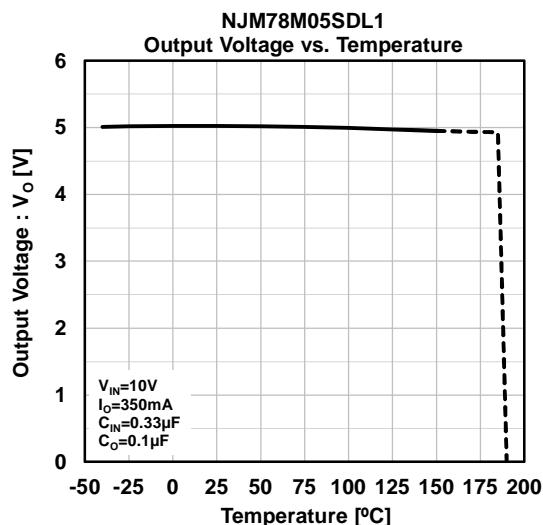
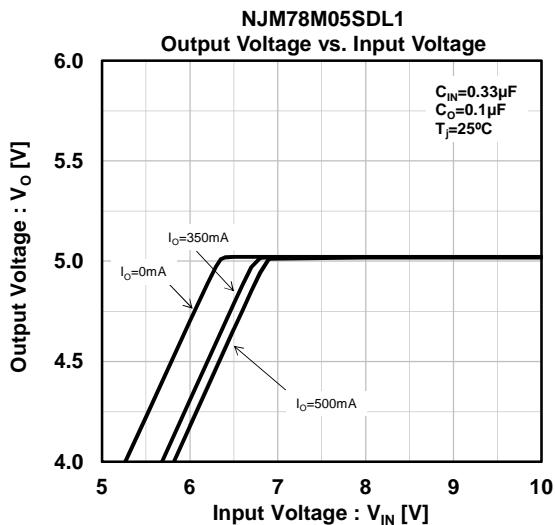
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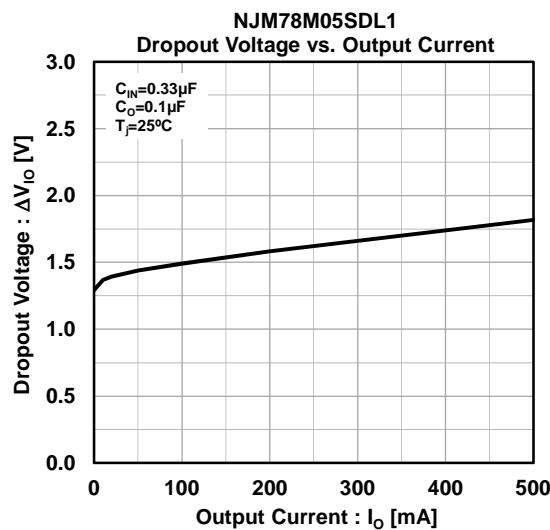
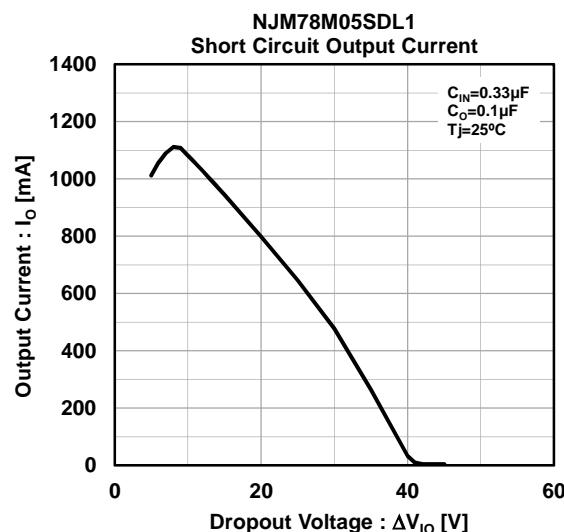
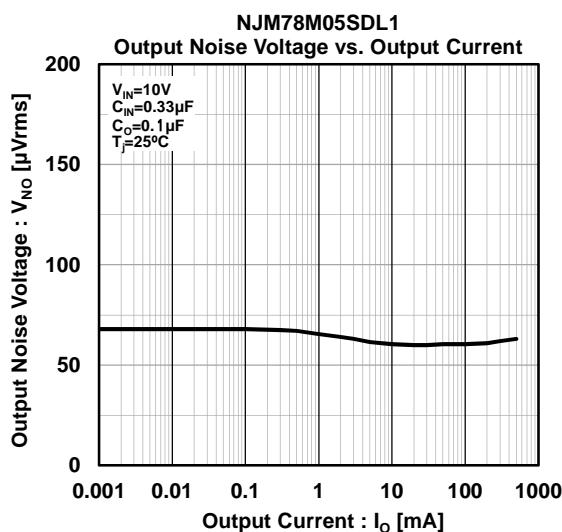
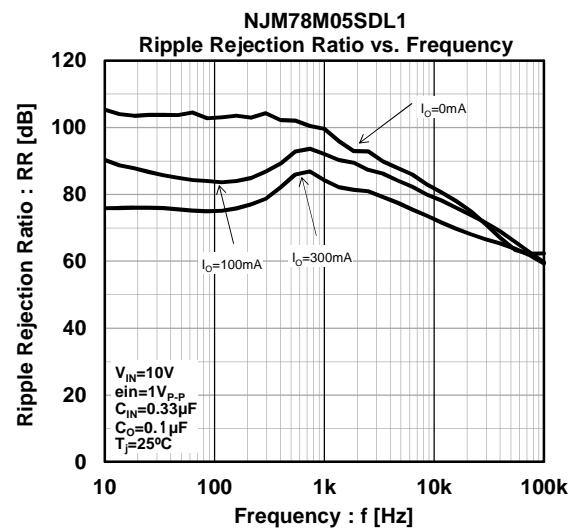
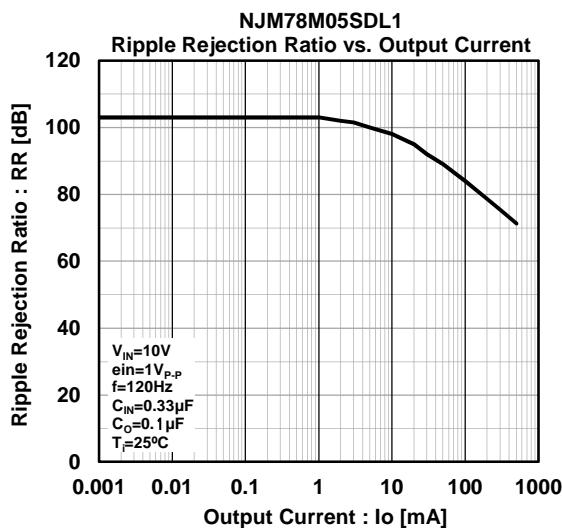
(4Layers inner foil: 74.2 ×74.2mm applying a thermal via hole to a board based on JEDEC standard JESD51-5)

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■TYPICAL CHARACTERISTICS (5V)

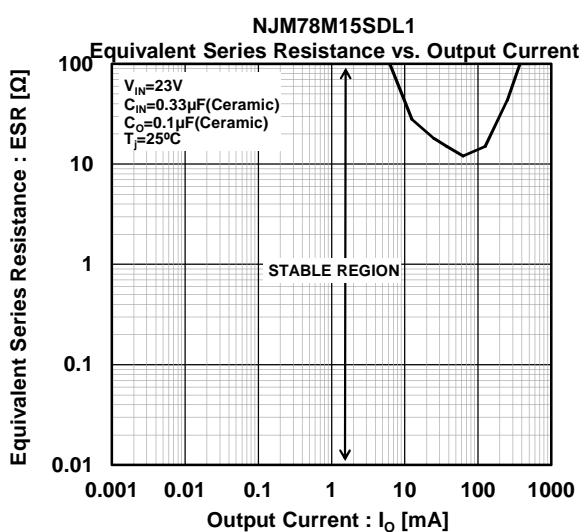
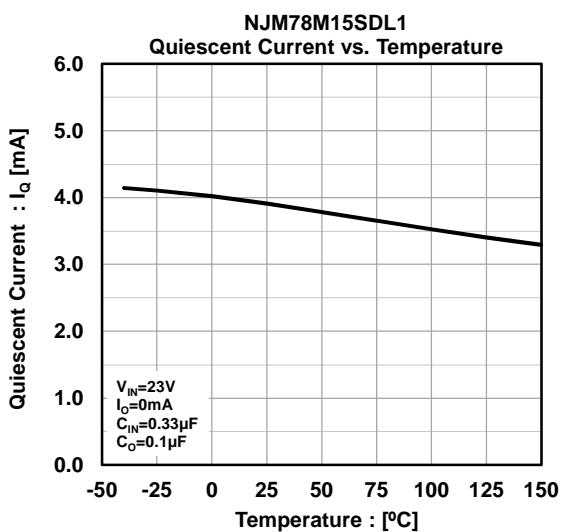
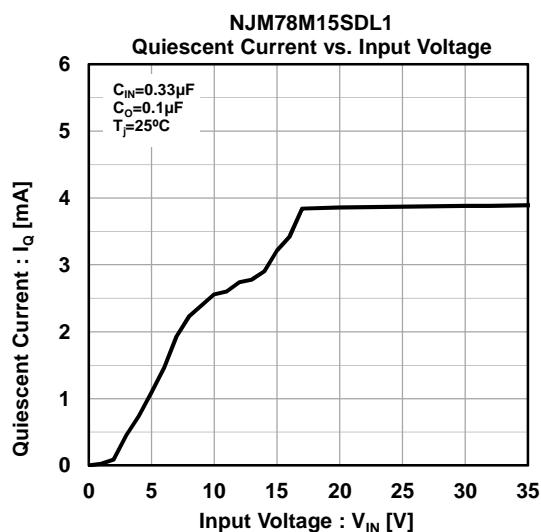
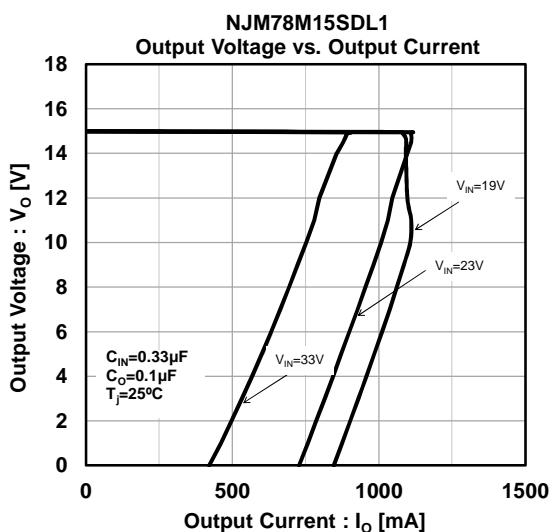
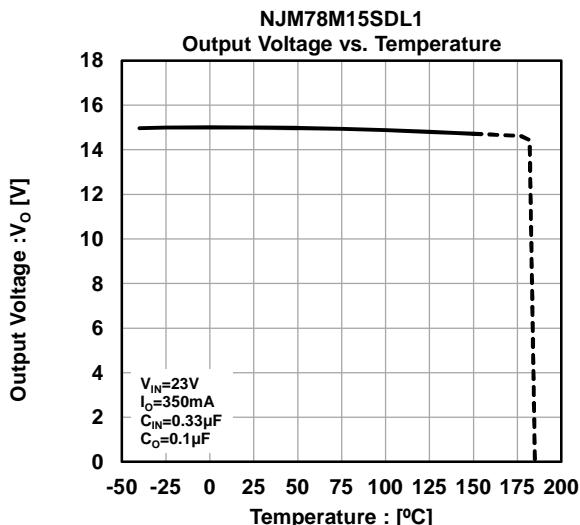
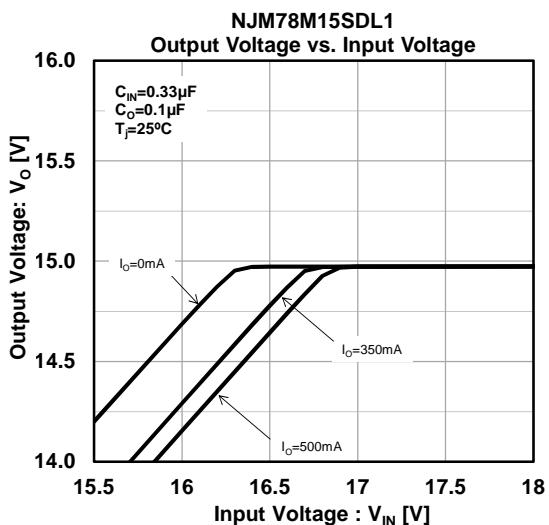


■TYPICAL CHARACTERISTICS (5V)

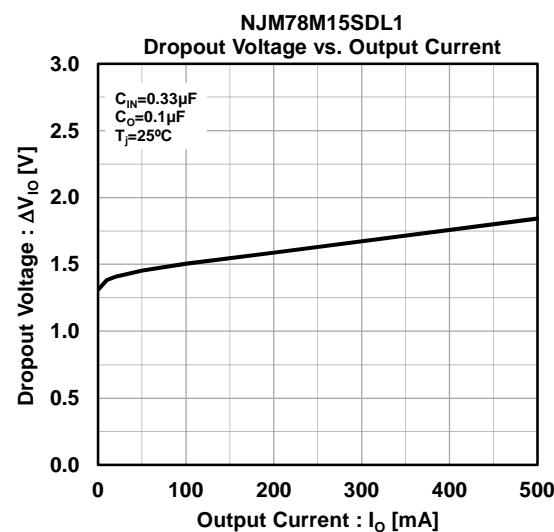
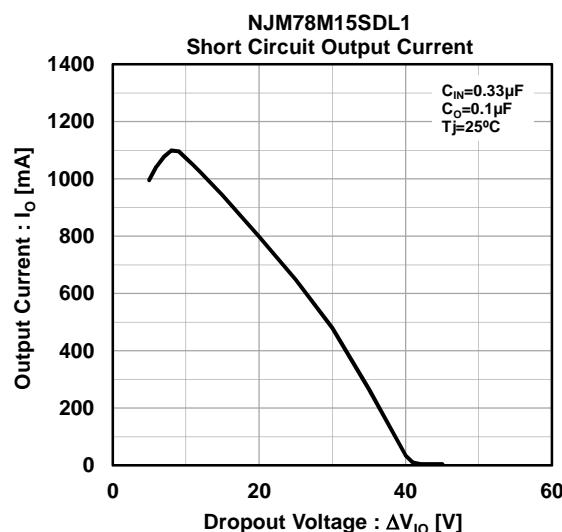
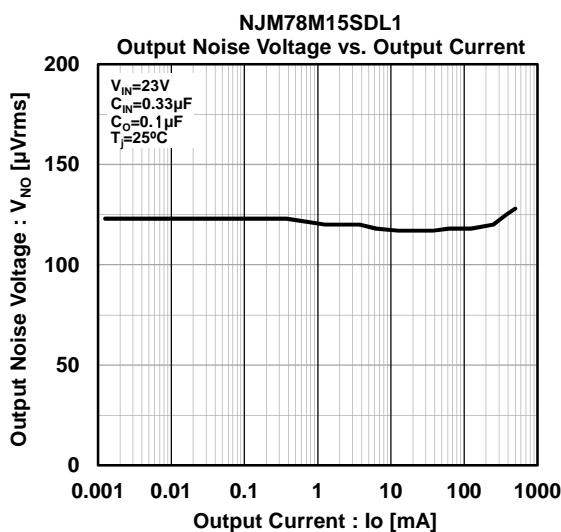
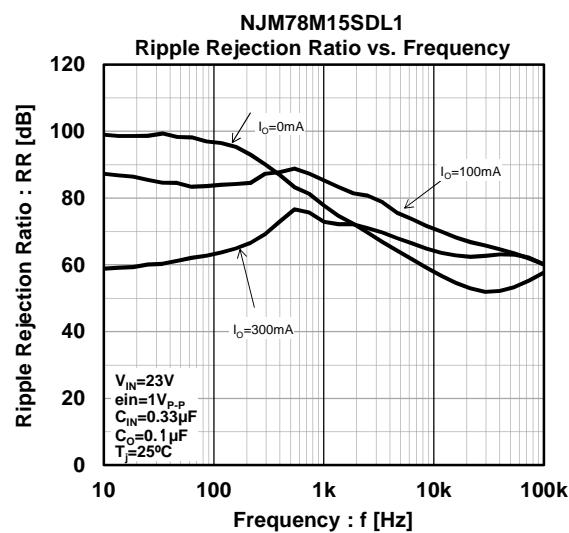
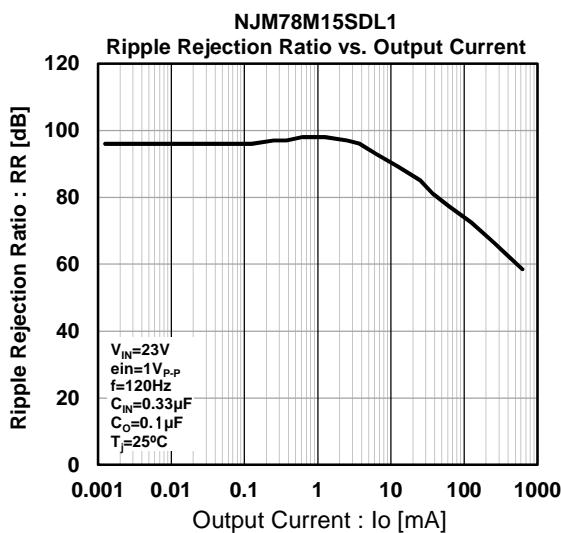


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■TYPICAL CHARACTERISTICS (15V)



■TYPICAL CHARACTERISTICS (15V)



MEMO

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